NSN 5961-01-115-6676

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-115-6676 **Inclosure Material:** Plastic **Overall Length:** 0.450 inches **Overall Height:** 0.130 inches **Overall Width:** 0.330 inches **End Application:** Pwrspyr2129/u **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 300.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 4.00 amperes forward current, total rms horsepower metric **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 110.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release6222 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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